First and second deprotonation of H₂SO₄ on wet hydroxylated (0001) α-quartz: Electronic Supplementary Information (ESI)

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1 Isomeric water monolayers on hydroxylated (0001) α -quartz

Figure S1 shows the three possible H-down monolayer water structures differing by an overall 120° rotation and their energies. We find that the energies of the three structures differ by less than 1 kcal/mol, with our structure (Figure S1(a)) used here and in ref.¹ being lowest in energy.

2 Validation of theory level

We confirmed that the level of theory used for the majority of the calculations, BLYP-D2/DZVP, correctly recovered the interior and surface structure of hydroxylated (0001) α -quartz without and with the physisorbed water layer, as well as the adsorption energy of the water layer. This is shown in Figure S2 and Figure S3, respectively, and in the corresponding tables, Table S1 and Table S2, respectively.

In Table S1, it is seen that the experimental interior Si-O distance and O-Si-O angle of dry α -quartz are both well recovered by BLYP-D2 with both the DZVP and TZV2P basis sets. Comparing to Table S2, it is seen that these parameters barely change upon adsorption of the water layer. This demonstrates that our quartz layer is thick enough so that the interior structure is maintained despite surface hydroxylation or additional water physisorption.

The importance of the dispersion correction in improving the water layer-surface separation and the adsorption energy per water molecule (E_{ads}) is seen in Table S2 (compare, e.g., the BLYP/DZVP and BLYP-D2/DZVP values). E_{ads} obtained with the smaller basis set DZVP is about 15% more negative than that obtained with TZV2P (note we have not corrected for the basis set superposition error). However, given the good agreement in geometries and therefore energy gradients, the smaller basis set performs well for the dynamics. Furthermore, as shown in the main text, we observed similar behavior for both basis sets for the interaction of sulfuric acid with the wet quartz surface and also of its dissociation mechanisms and time scale. Thus we conclude that use of the DZVP basis set for the majority of the calculations is an excellent compromise between accuracy and efficiency.

A *k*-point expansion is not implemented in CP2K. Thus, to test the validity of our setup and Γ -point only calculations with respect to *k*-point convergence, two checks were performed.

Firstly, we compared the water on quartz adsorption energy obtained in the literature calculations^{2,3} of wet hydroxylated (0001) α -quartz using the DFT PW91 functional (with a plane-wave basis set; calculation converged with regard to a *k*-point expansion). Since CP2K does not implement PW91, PBE was used (without the dispersion correction but with the TZV2P basis set to more closely model the plane-wave calculation). The value obtained for E_{ads} was very close to that in refs.^{2,3} (CP2K with original system size and PBE/TZV2P, -15.77 kcal/mol; VASP calculation using PW91 with a plane-wave basis set, converged with respect to a *k*-point expansion, -15.0 kcal/mol and -15.2 kcal/mol obtained in refs.^{2,3}). (Note also that the geometry obtained with PBE was close to that obtained with BLYP, which shows that the structure is relatively insensitive to the DFT functional used.)

As a second test to confirm the *k*-point convergence of our initial system size, we considered the system with the surface doubled in both in-plane dimensions. The calculations for this larger system (performed with BLYP-D2/DZVP) resulted in a geometry (not shown here) nearly identical to that of the original system. Finally, as shown in Table S2, the adsorption energies per physisorbed water molecule E_{ads} were also nearly the same (original system, -20.34 kcal/mol; large, doubled system, -20.60 kcal/mol).

This validates our use of the initial system size, calculated at the Γ -point implemented in CP2K, for the majority of the calculations.

3 Trajectory details

The initial conditions for the trajectories were developed as follows. Starting with the small system and the DZVP basis set, we calculated two trajectories which differed only in the initial lateral position and orientation of the sulfuric acid molecule relative to the surface. The acid was initially placed approximately 3.5 Å above the water layer and allowed to fall in *NVE* simulations at 250 K unto the equilibrated wet quartz surface. The initial H_2SO_4 rotamer was *trans*, which is lowest in energy (see ref.⁴ for a discussion H_2SO_4 rotamers). In some cases, the act of falling toward the surface and interacting with the surface prior to possible deprotonation caused the acid to cycle through its rotamer states, in a few cases ending up in the *cis* state, leading to a double H-bond donor bonding configuration, an unfavored situation for deprotonation. Trajectory 1 (acid is still a *trans* rotamer upon interacting with the surface) resulted in dissociation while Trajectory 2 (acid has become a *cis* rotamer) did not. The starting configurations of the acid in Trajectories 1 and 2 were used in the runs with the larger basis set (Trajectories 3 and 4), the Large system (Trajectories 5 and 6), and at the higher temperatures (Trajectories 18 and 19; 20 and 21; and 22 and 23). This use of nearly identical starting points allowed a better understanding of, e.g., the effect on deprotonation mechanisms and time scales due to an increase in temperature (or a change in basis set) and allowed us to sidestep extensive sampling at, for example, each temperature.

It is noteworthy that the deprotonation mechanisms and time scale in the Large system were similar to those in the Small system. We can compare, e.g., in Table S3, Trajectory 5, Large system, deprotonation time of 0.49 ps, with 5 H-bonds; to Trajectory 17, Small system, deprotonation time of 0.38 ps, with 4 H-bonds. In both trajectories, a similar process of further proton migration was then observed, forming the SSIP state, etc. Thus, the possible acid coverage effect, especially the electrostatic interaction between the replica ions in neighboring PBC cells after the initial ionization (the smallest separation between replicas is just our smallest PBC dimension, 8.504 Å), did not effect these mechanisms and time scales. This was true for the coverages we have considered. Presumably, if the acid coverages had been doubled (by, for example, reducing in half one of the surface dimensions in our Small cell), an effect due to the electrostatic interaction would be observed. However, we have not considered a larger acid coverage since it is not atmospherically relevant.

To further sample the possible outcomes at 250 K, additional trajectories with the Small system

and the DZVP basis set were run. They differed in the initial orientation, lateral position, and for some, the initial height of the H_2SO_4 molecule above the surface (thereby allowing for a steering effect of the surface). We observed the acid impacting on both types of water molecules (H-flat water molecules, WI; or H-down water molecules, WII), in different orientations and conformations, and in different H-bonding environments. The majority of the trajectories were calculated at 250 K. Deprotonation was favored, with 65% of all trajectories observed to deprotonate. Most deprotonations occurred within 1 ps. In six cases dissociation was not observed within the 5–10 ps duration of the trajectory. Three of the undissociated cases corresponded to the acid in a *cis* or *cis*-like conformation donating both its H-bonds to the surface waters simultaneously, an unfavorable situation since a free acid OH is necessary for the other proton to dissociate. In the other three cases, there was insufficient solvation of the oxygens of H_2SO_4 by water hydrogens (cluster studies suggest at least three H-bonds are required). Details can be found in Table S3.

4 Deprotonation mechanisms (300 K)

See Figure S4 and Figure S5. Note that these typical deprotonation mechanisms at 300 K are similar to those at 250 K.

5 Example of a proton wire (250 K)

See Figure S6.

6 Arrhenius behavior of deprotonation rate

Figure S7 displays an Arrhenius plot of the deprotonation rate as a function of temperature. The data are from Table S3 and show the average temperatures and the estimated average dissociation times for Trajectories 1, 18, 20, and 22. For the latter three higher trajectories/temperatures, extensive sampling was not performed but the use of nearly identical starting points (see Section 3) and

the observation of similar deprotonation mechanisms allowed use of scaling.

The expense of *ab initio* molecular dynamics precluded performing simulations at a larger number of temperatures. The sparsity of the data allows only the tentative observation that the deprotonation rate appears to display an Arrhenius behavior.

7 Disordering of the water layer as a result of proton migration (250 K)

See Figure S8 and Figure S9.

8 Comparison of spectroscopic signatures at 250 and 300 K

In Figure S10 the vibrational signatures of a typical dissociating trajectory at 300 K are compared to one at 250 K. Since the mechanisms and structures at the two temperatures are very similar, the corresponding spectra are also broadly similar, with the ionization leading to the presence of the hydronium continuum and a weak bisulfate or free OH signal at both temperatures (compare Figure S4(a) and Figure S4(d) to the very similar structures at 250 K in Figure 3(a) and Figure 3(d) in the main text).

9 Low energy configurations and bonding motifs of H₂SO₄ on wet quartz from geometry optimizations

In order to better understand the energetics, some points along the trajectories (H-bonded neutral H_2SO_4 in *cis* or *trans* rotamer configurations and dissociated H_2SO_4 , CIP or SSIP) were reoptimized. The results are presented in Table S4, and in Figure S11, Figure S12, and Figure S13. It is seen that the neutral, H_2SO_4 which donates both of its hydrogen atoms to water oxygens (which requires that H_2SO_4 be in its *cis* rotamer conformation) is by far the lowest energy structure. The lowest *trans* rotamer neutral is 5.9 kcal/mol higher in energy and the lowest energy dissociated configuration (SSIP) is 6.3 kcal/mol higher in energy. In contradiction to our results, in the work of Re et al.⁵ on H₂SO₄ in water clusters it was found that the ionized clusters were lower in energy for clusters with up to 5 waters. We can rationalize our result by observing that in our case of surface adsorption, the waters are on one side of the H₂SO₄ molecule only, and thus H₂SO₄ is in a *m*icro-solvated environment in which the undissociated *cis* rotamer conformation can be lowest in energy. However, in most of our trajectories, dissociation did occur, and thus the H₂SO₄ double H-donor configuration does not seem to be favored at finite temperatures, i.e., the free energy favors dissociation, and we may conjecture that even our H₂SO₄ double H-donor trajectories will eventually dissociate if the trajectories are extended in time.

The endothermicity of H_2SO_4 deprotonation in the micro-solvated environment of a vaporwater or vapor-ice interface has been observed in the work of Hynes, Bianco, and coworkers,^{6–8} who also observed the discrepancy between energy and free energy and the importance and critical effect of temperature on H_2SO_4 deprotonation by computational modeling of H_2SO_4 embedded at the liquid-vapor interface.⁷ They determined that at the interface, the likelihood of deprotonation is very sensitive to both solvation and temperature.⁷ Thus, while energy minimizations at 0 K are useful for examining structures and attachment energies of the acid at various sites, they should be not a guide to judging the feasibility of deprotonation at finite temperatures. For that, our molecular dynamics simulations are a more reliable measure.

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orange; oxygen, red; hydrogen, white; silicon, yellow) and relative energies E_{rel} and water binding energies E_b (per water monomer on the hydroxylated (0001) α -quartz surface, relative to the optimized isolated dry hydroxylated surface and the isolated single water monomer). The structures and energies were obtained using CP2K and BLYP-D2 always with the appropriate GTH pseudopotentials Figure S1: The three geometry-optimized water adlayer isomer structures (perspective view; silanol top layer only shown; sulfur, and the DZVP basis set (the structures obtained using the TZV2P basis set were nearly identical; the TZV2P energies are shown in parentheses). All energies are in kcal/mol.



(a) Dry surface: Top view



(b) Dry surface: Side view

Figure S2: Images of the optimized hydroxylated (0001) α -quartz surface and its geometrical parameters obtained using CP2K and BLYP-D2/DZVP. Dry surface (without physisorbed water): (a) top view (silanol top layer only shown) and (b) side view.



(a) Wet surface: Top view



(b) Wet surface: Side view

Figure S3: Images of the optimized hydroxylated (0001) α -quartz surface and its geometrical parameters obtained using CP2K and BLYP-D2/DZVP. Wet surface (containing the single physisorbed water monolayer): (a) top view (silanol top layer only shown) and (b) side view.

Table S1: Theory level validation: Geometric parameters of the dry α -quartz system obtained with various DFT functionals and basis sets^a

Quantity	Description	BLYP/DZVP	BLYP-D2/DZVP	BLYP/TZV2P	BLYP-D2/TZV2P	PBE/TZV2P	PW91	Expt
		Geomet	ric parameters: top vie	w (see Figure S2(a)))			
r _{Si-OH}	SI, internal bond	1.68	1.68	1.66	1.66	1.66		
r _{Si-OH}	SII, internal bond	1.67	1.67	1.64	1.65	1.64		
θ_{O-Si-O}	SII-SI, internal, angle	109.85	111.08	109.21	110.22	109.57		
r _{SiO-H}	SI, internal bond	1.00	1.00	0.99	0.99	0.99		
r _{SiO-H}	SII, internal bond	1.00	1.00	0.99	0.99	0.99		
$\theta_{\rm Si-O-H}$	SI, internal, angle	111.82	111.88	113.20	113.18	112.14		
θ_{Si-O-H}	SII, internal, angle	113.27	112.40	114.49	114.16	114.28		
r _{SiOH-OSi}	SII-SI, strong h-bond	1.79	1.78	1.80	1.81	1.78	1.74^{b}	
rsiOH-OSi	SI-SII, weak h-bond	2.03	2.03	2.08	2.08	2.10	2.11 ^b	
θ_{H-O-Si}	SII-SI, strong h-bond, angle	132.09	132.69	133.72	133.99	133.72		
θ_{O-H-O}	SI-SII, weak h-bond, angle	169.18	170.51	167.93	169.04	168.95	168 ^b	
θ_{H-O-H}	SI-SII, weak h-bond, angle	111.92	111.18	109.91	109.09	110.62		
r_{0-0}	silanol O - silanol O, distance 1		2.76			2.71	2.72^{b}	
r_{0-0}	silanol O - silanol O, distance 2		2.78			2.77	2.73 ^b	
r ₀₋₀	silanol O - silanol O, distance 3		3.02			3.08	3.09^{b}	
		Geometr	ic parameters: side vi	ew (see Figure S2(b))			
r_{Si-O}	α -quartz, internal bond	1.66	1.66	1.64	1.64	1.64		1.61 ^c
θ_{O-Si-O}	α -quartz, internal, angle	107.28	108.18	108.02	108.69	108.55		$109^{c,d}$
$\theta_{Si-O-Si}$	α -quartz, internal, angle	140.76	138.24	143.50	140.55	142.25		144 ^c

^{*a*} All geometry optimizations were performed with CP2K and the indicated DFT functional and basis set. Bond lengths and bond angles are in Å and degrees, respectively. SI and SII refer to the two populations of silanols SiOH on which in the wet system are adsorbed the two populations of water molecules WI and WII, respectively. ^{*b*} Calculation with VASP and PW91 (with a plane-wave basis set; calculation converged with regard to a *k*-point expansion), ref.² ^{*c*} Experimental values are listed in ref.⁹ ^{*d*} The median value of the measured angle is 109°. The four measured values ⁹ are 108.57°, 108.72°, 108.97°, and 110.66°.

Table S2: Theory level validation: Geometric parameters and water molecule adsorption energy of the wet α -quartz system obtained with various DFT functionals and basis sets^{*a*}

Geometric parameters: top view (see Figure S3(a)) r_{0-H1} WI, internal bond 1.00 1.00 0.99 0.09 0.09 q_{0-H1} WI, internal, angle 10.0 1.00 0.99 0.99 0.99 $q_{H1-O-H2}$ WI, internal, angle 10.7.18 107.52 107.91 107.65 $rH1-O$ WI-WI, weak h-bond 3 1.82 1.83 1.83 1.82 1.82 $rH1-O$ WI-WI, weak h-bond 1 1.92 1.94 1.92 1.93 1.94 $q_{12-O-H1}$ WI-WI, weak h-bond 3, angle 116.41 116.27 115.52 164.55 q_{O-H1-O} WI-WI, weak h-bond 2, angle 157.44 158.59 157.99 158.42 q_{O-H1-O} WII-WI, weak h-bond 2, angle 159.33 158.93 158.92 159.15 185.53 r_{O-O} silanol O, distance 1 2.55 2.58 2.55^{h.d.} r_{O-O} silanol O, distance 1 2.76 2.68 2.67^{h.d.} r_{O-O} silanol O, distance 1	Quantity	Description	BLYP/DZVP	BLYP-D2/DZVP	BLYP/TZV2P	BLYP-D2/TZV2P	PBE/TZV2P	PW91
$\begin{array}{cccccccccccccccccccccccccccccccccccc$			Geometric par	ameters: top view (see	e Figure S3(a))			
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	r _{O-H1}	WI, internal bond	1.00	1.00	0.99	1.00	0.99	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	r _{O-H1}	WII, internal bond	1.00	1.00	0.99	0.99	0.99	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\theta_{\rm H1-O-H2}$	WI, internal, angle	107.18	107.53	107.52	107.91	107.65	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	r _{H1-O}	WI-WII, weak h-bond 3	1.82	1.81	1.83	1.82	1.82	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	r _{H2-O}	WI-WII, weak h-bond 2	1.88	1.86	1.89	1.88	1.88	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$r_{\rm H1-O}$	WII-WI, weak h-bond 1	1.92	1.94	1.92	1.93	1.94	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	$\theta_{\rm H2-O-H1}$	WI-WII, weak h-bond 3, angle	116.41	116.27	116.27	115.99	115.64	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	θ_{O-H2-O}	WI-WII, weak h-bond 3, angle	163.14	164.55	163.91	165.24	164.55	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	θ_{O-H1-O}	WI-WII, weak h-bond 2, angle	157.44	158.59	157.99	159.29	158.42	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\theta_{\rm H1-O-H2}$	WII-WI, weak h-bond 1, angle	119.59	119.11	120.06	120.30	120.57	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	θ_{O-H1-O}	WII-WI, weak h-bond 1, angle	159.33	158.93	158.92	159.15	158.53	
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	r _{O-0}	silanol O - silanol O, distance 1		2.55			2.58	$2.55^{b,d}$
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	<i>r</i> 0–0	silanol O - silanol O, distance 2		2.65			2.61	$2.63^{b,d}$
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	r ₀₋₀	silanol O - silanol O, distance 3		3.38			3.42	$3.44^{b,d}$
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	r ₀₋₀	silanol O - water O, distance 1		2.76			2.68	$2.67^{b,d}$
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	r ₀₋₀	silanol O - water O, distance 2		2.78			2.70	$2.72^{b,d}$
r_{O-O} water O, water O, distance 2 2.82 2.89 2.87 ^{b,d} Geometric parameters: side view (see Figure S3(b)) r_{Si-O} α -quartz, internal, angle 106.68 1.66 1.64 1.64 1.64 θ_{O-Si-O} α -quartz, internal, angle 106.68 107.60 107.61 108.77 107.83 $\theta_{Si-O-Si}$ α -quartz, internal, angle 141.45 138.94 144.20 140.68 143.59 $\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 140.34 137.09 139.07 r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_O-HI WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_SiOH-OSi$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 $r_SiOH-OSi$ SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WII-SIII, strong h-bond 3 1.72 1.66	$r_{\Omega-\Omega}$	water O - water O, distance 1		2.80			2.83	$2.77^{b,d}$
Geometric parameters: side view (see Figure S3(b)) r_{Si-O} α -quartz, internal bond 1.66 1.66 1.64 1.64 θ_{O-Si-O} α -quartz, internal, angle 106.68 107.60 107.61 108.77 107.83 $\theta_{Si-O-Si}$ α -quartz, internal, angle 141.45 138.94 144.20 140.68 143.59 $\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 140.34 137.09 139.07 r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal bond 1.00 1.00 0.99 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 $r_{SiOH-OSi}$ SI-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-O} WII-SII, strong h-bond 3 1.72 1.66	r0-0	water O - water O, distance 2		2.82			2.89	$2.87^{b,d}$
Geometric parameters: side view (see Figure S3(b)) Geometric parameters: side view (see Figure S3(b)) r_{Si-O} α -quartz, internal angle 1.66 1.66 1.64 1.64 θ_{O-Si-O} α -quartz, internal, angle 106.68 107.60 107.61 108.77 107.83 $\theta_{Si-O-Si}$ α -quartz, internal, angle 141.45 138.94 144.20 140.68 143.59 $\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 100.34 137.09 139.07 r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal ond 1.00 1.00 0.99 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 $r_{SiOH-OSi}$ SI-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 $r_{$								
r_{Si-O} α -quartz, internal bond 1.66 1.66 1.64 1.64 1.64 θ_{O-Si-O} α -quartz, internal, angle 106.68 107.60 107.61 108.77 107.83 $\theta_{Si-O-Si}$ α -quartz, internal, angle 141.45 138.94 144.20 140.68 137.99 $\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 140.34 137.09 139.07 r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal bond 1.02 10.3 1.00 0.99 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 10.82 102.04 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.72 1.66 1.76 1.69 1.70 r_{H2-OSi} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 <td></td> <td></td> <td>Geometric par</td> <td>ameters: side view (se</td> <td>e Figure S3(b))</td> <td></td> <td></td> <td></td>			Geometric par	ameters: side view (se	e Figure S3(b))			
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$	r _{Si-O}	α -quartz, internal bond	1.66	1.66	1.64	1.64	1.64	
$\theta_{Si-O-Si}$ α -quartz, internal, angle 141.45 138.94 144.20 140.68 143.59 $\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 140.34 137.09 139.07 σ_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal bond 1.00 1.00 0.99 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 $r_{SiOH-OSi}$ SI-SII, strong h-bond 2 1.69 1.72 1.66 1.76 1.69 1.70 r_{H2-OSi} WII-Sill, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-OSi} WII-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78	θ_{O-Si-O}	α -quartz, internal, angle	106.68	107.60	107.61	108.77	107.83	
$\theta_{Si-O-Si}$ α -quartz, internal, angle 137.95 134.85 140.34 137.09 139.07 r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal bond 1.00 1.00 0.99 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.70 r_{H2-OSi} WI-SII, strong h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 ψ_{H2} ψ_{H2} ψ_{H2} ψ_{H2} ψ_{H2} ψ_{H2} ψ_{H2} ψ_{H2}	$\theta_{Si-O-Si}$	α -quartz, internal, angle	141.45	138.94	144.20	140.68	143.59	
r_{SiO-H} SI, internal bond 1.02 1.03 1.00 1.01 1.01 r_{O-HI} WII, internal bond 1.00 1.00 0.99 0.99 0.99 $p_{H1-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WI-SII, strong h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 $\theta_{SiOH-O-H2}$ WI-WIL mode h and 0 angle 80.72 80.07 80.02 00.57 80.20	$\theta_{Si-O-Si}$	α -quartz, internal, angle	137.95	134.85	140.34	137.09	139.07	
r_{O-HI} WII, internal bond 1.00 0.09 0.99 0.99 $\theta_{HI-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 $r_{SiOH-OSi}$ SI-SII, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WII-SIII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-O} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46	r _{SiO-H}	SI, internal bond	1.02	1.03	1.00	1.01	1.01	
$\theta_{H1-O-H2}$ WII, internal, angle 101.82 102.04 102.67 102.72 102.32 $r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.57 r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WII-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-OSi} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 $\theta_{SiOH-O-H2}$ WIL work h-bond 2, angle 104.76 104.38 103.85 102.78 103.46	r _{O-H1}	WII, internal bond	1.00	1.00	0.99	0.99	0.99	
$r_{SiOH-OSi}$ SI-SII, strong h-bond 1 1.56 1.57 1.60 1.60 1.57 r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WI-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-OSi} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46	$\theta_{H1-O-H2}$	WII, internal, angle	101.82	102.04	102.67	102.72	102.32	
r_{SiOH-O} SI-WI, strong h-bond 2 1.69 1.63 1.75 1.69 1.67 r_{H2-OSi} WII-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-O} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 WII WII weak h-bond 2 90.72 90.07 90.92 00.57 80.20	rSiOH-OSi	SI-SII, strong h-bond 1	1.56	1.57	1.60	1.60	1.57	
r_{H2-OSi} WII-SII, strong h-bond 3 1.72 1.66 1.76 1.69 1.70 r_{H2-O} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 WII Will work h band 2 angle 80.72 80.07 80.02 00.57 80.02	r _{SiOH-O}	SI-WI, strong h-bond 2	1.69	1.63	1.75	1.69	1.67	
r_{H2-O} WI-WII, weak h-bond 2 1.88 1.86 1.89 1.87 1.88 $\theta_{SiOH-O-H2}$ SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 WI Will work h band 2 angle 0.07 00.02 00.57 80.20	r _{H2-OSi}	WII-SII, strong h-bond 3	1.72	1.66	1.76	1.69	1.70	
θ _{SiOH-O-H2} SI-WI, strong h-bond 2, angle 104.76 104.38 103.85 102.78 103.46 WI WI with the and a ciple 80.72 80.07 80.02 00.57 80.02	$r_{\rm H2-O}$	WI-WII, weak h-bond 2	1.88	1.86	1.89	1.87	1.88	
0 WI WII week h herd 2 angle 90.72 90.07 90.02 00.57 90.20	$\theta_{SiOH-O-H2}$	SI-WI, strong h-bond 2, angle	104.76	104.38	103.85	102.78	103.46	
$\sigma_{\text{H2}=\text{O}=\text{H2}}$ w1-w11, weak in-bolid 2, angle 69.72 89.97 89.92 90.57 89.39	$\theta_{\rm H2-O-H2}$	WI-WII, weak h-bond 2, angle	89.72	89.97	89.92	90.57	89.39	
			Adaam	tion on one unon U. O.	n lavan			
Austricular energy per H_2O in layer	r	A 1	Adsor	20.24	in iayer	17.07	15 77	15 ohd
E_{ads} Ausorption energy -15.80 -20.34 -12.89 -17.27 -15.77 -	Lads	Ausorption energy	-15.86	-20.34	-12.89	-1/.2/	-15.//	-15.0°,"
(Doubled surface) (-20.60)		(Doubled surface)		(-20.60)				-15.2°,"

^{*a*} All geometry optimizations were performed with CP2K and the indicated DFT functional and basis set. Bond lengths and bond angles are in Å and degrees, respectively. The adsorption energy (per water molecule, in kcal/mol) $E_{ads} = (E_{total} - E_{surf} - nE_{H_2O})/n$, where E_{total} is the energy of the surface including a monolayer of water, E_{surf} is the energy for the optimized clean hydroxylated surface system, E_{H_2O} is the energy for an isolated water molecule, and ris the number of adsorbed water molecules. SI and SII refer to the two populations of silanols SiOH on which in the west system are adsorbed the two populations of vater molecules WI and WII, respectively. ^bCalculation with VASP and PW91 (with a plane-wave basis set; calculation converged with regard to a *k*-point expansion), ref.²

^CCalculation with VASP and PW91 (with a plane-wave basis set; calculation converged with regard to a *k*-point expansion), ref. ³ ^dNote that the water adlayer computed in refs. ^{2,3} is slightly different, differing by an overall rotation of 120° relative to the one computed by us. Nevertheless, the various O-O separation distances and adsorption energies are nearly identical, justifying our comparison with the results obtained in refs. ^{2,3}

Comments			H ₂ SO ₄ is a double H-bond donor.	Dissociates briefly at 0.87 ps.	Insufficient solvation.		Insufficient solvation.	H ₂ SO ₄ is a double H-bond donor.				Insufficient solvation.	H ₂ SO ₄ is double H-bond donor.			Dissociates late; reforms neutral within 0.3 ps;	thus no further PT.	Proton wire leads to reformation of neutral within 0.3 ns.			Reforms neutral and dissociates again at 1.26 ps.	H ₂ SO ₄ is a double H-bond donor.		H ₂ SO ₄ is a double H-bond donor.		H ₂ SO ₄ is a double H-bond donor.
	further PT?	Y	na	maybe	na	Y	na	na	Y	Y	Y	na	na	Y	Y	z		Y	Υ		Y	na	Y	na	Y	na
otonation?	HSO ₄ ⁻ H-bonds	4	na	4	na	5	na	na	3	4	4	na	na	ŝ	5	3		4	4		5	na	5	na	4	na
Depro	to	MII	na	Μ	na	IW	na	na	ШM	ШM	ШM	na	na	ШM	ШM	IM		ШM	IW		ШМ	na	ШM	na	ΙM	na
	time t [ps]	0.92	na	2.19	na	0.49	na	na	0.39	0.58	0.72	na	na	1.02	0.54	4.63		0.58	0.38	1.1	0.58	na	0.58	na	0.47	na
		Y	z	Y	z	Y	z	z	Y	Y	Y	z	z	Y	Y	Y		Y	٢		γ	z	Υ	z	γ	z
-bonds	sum	4	4	4	-	5	-	0	ŝ	4	4	2	4	ŝ	5	ŝ		4	4		5	4	5	4	4	4
es/accepts F	accepts	m	7	3	0	4	0	0	5	3	33	-	2	2	4	2		7	3		4	2	4	7	ю	2
H ₂ SO ₄ donat	donates (to)	1 (WII)	2 (WI, WI)	1 (WI)	1 (WI)	1 (WI)	1 (WI)	2 (WI, WII)	1 (WII)	1 (WII)	1 (WII)	1 (WII)	2 (WI, WII)	1 (WII)	1 (WII)	1 (WI)		2 (WII, WII)	1 (WI)		1 (WII)	2 (WI, WII)	1 (WII)	2 (WI, WI)	1 (WI)	2 (WI, WII)
Duration	[bs]	10.00	5.00	6.55	9.61	6.37	5.08	5.00	5.00	5.00	5.00	5.00	5.00	5.00	5.00	5.00		5.00	5.00		5.00	5.00	10.00	5.00	5.00	5.00
X	ΔT	+16	+14	6+	*	Ľ+	ę	+18	+13	6+	+10	4	+21	+20	+19	+16		+14	+17	+13	+10	+17	+25	+18	+25	+18
nperature	T_{avg}	266	264	259	258	257	256	268	263	259	260	257	271	270	269	266		264	267	263	280	290	325	318	337	342
Ten	T_0	250	250	250	250	250	250	250	250	250	250	250	250	250	250	250		250	250		273	273	300	300	330	330
System		Small	Small	Small	Small	Large	Large	Small	Small	Small	Small	Small	Small	Small	Small	Small		Small	Small		Small	Small	Small	Small	Small	Small
Basis		DZVP	DZVP	TZV2P	TZV2P	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP	DZVP		DZVP	DZVP		DZVP	DZVP	DZVP	DZVP	DZVP	DZVP
Irajectory		_	2	3	4	5	9	7	×	6	10	Ξ	12	13	14	15		16	17	mean	18	19	20	21	22	23

Table S3: Summary of Trajectories 1–23^a showing whether the first H₂SO₄ deprotonation occurred and if so, the conditions.^b

^a Our 24th trajectory. Trajectory 5a, is not shown here since it describes a second deprotonation event. It is the continuation of Trajectory 5 after addition of a second water layer on top of HSO₄⁻ on wet quartz present at time of 6.37 ps in Trajectory 5. The duration of Trajectory 5 after addition of a second water layer on top of HSO₄⁻ on wet quartz present at time of 6.37 ps in Trajectory 5. The duration of Trajectory 5 a was 1.92 ps. ^b All calculations in the *NVE* ensemble employed CP2K and BLYP-D2 with the DZVP or TZV2P basis set, a time step of 0.4 fs, and proceeded from an equilibrated simulation with the identical basis set in the *NVT* ensemble at the target temperature. The H-bonding environment of H_2SO_4 and HSO_4^- is also shown. Y = yes, N = no, na = not applicable, PT = proton transport.



Figure S4: Snapshots showing the H_2SO_4 first deprotonation and subsequent proton migration at 300 K (perspective view; silanol top layer only shown; sulfur, orange; oxygen, red; hydrogen, white; silicon, yellow). In panel (d) the water molecule to which H^+ has transferred is located across the periodic boundary of the simulation cell, at the left side of the image. The data are from Trajectory 20.







Figure S5: Interatomic separations and partial Mulliken charges of relevant atoms during the proton migration at 300 K. The snapshot (at t = 0.00 ps) shows the atom labels. The black vertical lines draw attention to relevant time intervals. The data are from Trajectory 20. See also Figure S4(a)–(d) for geometries.

t [ps]

(a) t = 0.56 ps:



Figure S6: Snapshots from Trajectory 16 (250 K) showing waters acting as a proton wire to reform neutral H₂SO₄ with the proton on a different H₂SO₄ oxygen (perspective view; silanol top layer only shown).



Figure S7: Arrhenius plot for the rate $k = 1/t_{avg}$ of the first deprotonation of H₂SO₄ on wet quartz as a function of temperature.



(a) g_{OO} within the water layer (250 K)

(b) g_{OO} of bulk ice (250 K) and bulk water (300 K)

(c) g_{OH} within the water layer (250 K)



(d) g_{OH} of bulk ice (250 K) and bulk water (300 K)



Figure S8: Radial distribution functions within the water adlayer obtained over the indicated time intervals during the proton migration at 250 K (Trajectory 1) compared with those of neat bulk ice (250 K) and bulk water (300 K). The progressive disordering with time is visible.



Figure S9: Distributions of molecular orientations θ within the water adlayer obtained over the indicated time intervals during the proton migration at 250 K (Trajectory 1). The progressive disordering with time is visible. WI (in-plane waters) and WII (H-down waters) are the two populations of water molecules. θ is the angle between the water H-O-H bisector and the surface normal.

(a) t = 0.00 ps: Before introduction of H_2SO_4 to the surface (separate 5 ps trajectories)



(b) t = 1.11–7.07 ps (250 K) and 1.08–8.81 ps (300 K): After introduction of H_2SO_4 (existence of SSIP $HSO_4^- \cdots H_2O \cdots H_3O^+$)



Figure S10: Comparison of vibrational spectra (VDOS) during the proton migration at 250 and 300 K. VDOS were computed for the indicated time interval. In panel (b) (red curve), HSO_4^- causes the weak shoulder at about 3620 cm⁻¹ (free water OH also contributes in this region), and H_3O^+ causes the small increase in intensity in the broad region at 2800 cm⁻¹ and below. The data are from Trajectory 1 (250 K) and Trajectory 18 (300 K). See also Figure S4(a) and Figure S4(d) for the geometries corresponding to the 300 K spectra in panels (a) and (b), respectively. They can be compared to the very similar structures at 250 K₂in Figure 3(a) and Figure 3(d) in the main text.

Comments		Neutral (cis).	Neutral (other non-trans rotamer).	Neutral (other non-trans rotamer).	Neutral (other non-trans rotamer).	Neutral (trans).	Neutral (trans).	Neutral (trans).	Neutral (trans).	Ionized (SSIP).	Ionized (SSIP).	Ionized (CIP).	Ionized (CIP).
E_{int}		-29.5 (-23.8)	-28.9	-22.6	-20.9	-23.7	-20.0 (-15.2)	-19.8	-16.2	-23.3 (-17.7)	-21.7	-21.4	-17.2 (-12.5)
E_{rel}		(0.0) (0.0)	0.7	7.0	8.6	5.9	9.6 (8.7)	9.7	13.3	6.3 (6.2)	7.9	8.2	12.3 (11.3)
spuoc	sum	4	6	4	ε	3	6	6	ε	na	na	4	ŝ
/accepts H-h	accepts	2	-	2	-	2	-	-	2	na	na	ŝ	2
H ₂ SO ₄ donates	donates (to)	2 (WI, WII)	1 (WI)	2 (WII, WII)	2 (WII, WII)	1 (WII)	1 (WII)	1 (WII)	1 (WII)	na	na	1 (WI)	1 (WII)
Encountered in Trajectory		7	2	12	16	11	1	8	6	-	13	17	1
Structure name ^b		c-a	c-b	0-C	c-d	n-a	n-b	n-c	p-u	i-a	i-b	i-c	i-d

Table S4: Relative and interaction energies (all in kcal/mol) and characteristics of some minimum energy structures of neutral and deprotonated H_2SO_4 on the wet quartz surface.^{*a*} $^{a}E_{\text{Fel}}$ are relative energies with respect to the lowest energy configuration, the neutral *cis c*-a structure. Interaction energies $E_{\text{int}} = E(\text{configuration}) - E(\text{isolated H}_2\text{O}_4 \text{ molecule})$ (no correction for basis set superposition error). The starting point of these OK energy minimizations were some points in Trajectories 1–17 (exclude Trajectories 1–17) (exclude Trajectories 1–17) (exclude Trajectories 5 and 6) from Table S3. The H-bonding environment of H_3\text{O}_4 and HSO_7 is also shown as in Table S3. Calculations used the small system and CP2K with BLYP-D2 and the DZYP basis set results are points in parentheses, using the larger basis set does not change the geometries or the energy ordering of configurations. See also Figure S11. Figure S13 for the c (neutral *cis*), n (neutral *trans*) and (singly ionized. SSIP or CIP) configurations. respectively.

ionized/deprotomated H₂SO₄, i.e., bisulfate HSO₄), ii (doubly ionized/deprotomated H₂SO₄, i.e., sulfate SO₄²⁻, not observed in the smaller system); and the label y = a, b, c, ... labels each configuration type in order of increasing energy.

c-a: 0.0 kcal/mol



c-c: 7.0 kcal/mol



c-b: 0.7 kcal/mol



Figure S11: Some geometry-optimized c (neutral cis) configurations and their relative energies (calculated with the DZVP basis set; perspective view; silanol top layer only shown). Only the top portion of the quartz slab is shown. See Table S4 for details.

n-a: 5.9 kcal/mol



n-c: 9.7 kcal/mol



n-b: 9.6 kcal/mol



Figure S12: The n (neutral *trans*) configurations. See caption to Figure S11.





i-c: 8.2 kcal/mol (CIP)







Figure S13: The i (singly ionized, SSIP or CIP) configurations. See caption to Figure S11.